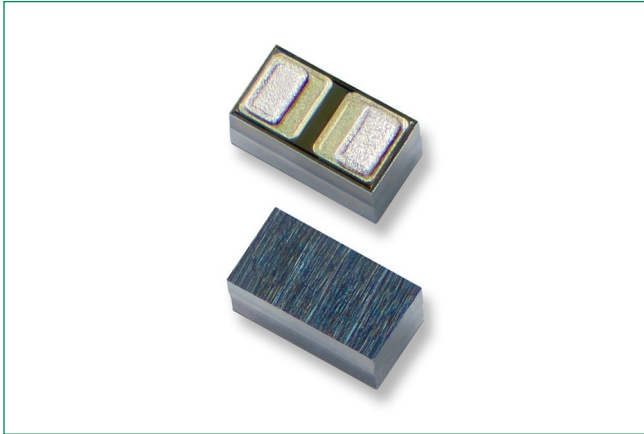


SPxx Series

100W Discrete Bidirectional TVS Diode

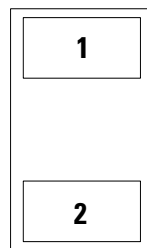


Web Resources

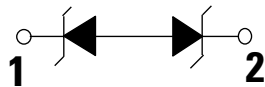


Download ECAD models, order samples, and find technical resources at www.littelfuse.com

Pinout



Functional Block Diagram



Description

The SPxx-01WTG-C-HV series is designed to replace multilayer varistors (MLVs) in portable applications, LED lighting modules, and low speed I/Os. It will protect sensitive equipment from damage due to electrostatic discharge (ESD) and other overvoltage transients.

The SPxx-01WTG-C-HV series can safely absorb repetitive ESD strikes above the maximum level of the IEC 61000-4-2 international standard (Level 4, $\pm 8\text{kV}$ contact discharge) without performance degradation and safely dissipate up to 8A (SP12-01WTG-C-HV) of induced surge current (IEC 61000-4-5, $t_p=8/20\mu\text{s}$) with very low clamping voltages.

Features & Benefits

- ESD, IEC 61000-4-2, $\pm 30\text{kV}$ contact, $\pm 30\text{kV}$ air
- EFT, IEC 61000-4-4, 40A (5/50ns)
- IEC 61000-4-5, 2nd Edition: 8/20 Surge, 8A Surge Immunity. SP12-01WTG-C-HV.
- Low clamping voltage
- Low leakage current
- Halogen free, Lead free and RoHS compliant

Applications

- LED Lighting Modules
- Portable Instrumentation
- General Purpose I/O
- Mobile & Handhelds
- RS232 / RS485
- CAN bus

Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

SPxx Series

100W Discrete Bidirectional TVS Diode

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
P_{pk}	Peak Pulse Power ($t_p=8/20\mu s$)	100	W
T_{OP}	Operating Temperature	-40 to 125	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

Caution: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Thermal Information

Parameter	Rating	Units
Maximum Junction Temperature	150	°C
Maximum Lead Temperature (Soldering 20-40s)	260	°C

SP12-01WTG-C-HV Electrical Characteristics ($T_{OP}=25^\circ C$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1\mu A$			12.0	V
Reverse Breakdown Voltage	V_{BR}	$I_R = 1mA$	13.3			V
Leakage Current	I_{LEAK}	$V_R = 12V$			0.1	μA
Clamp Voltage ¹	V_C	$I_{PP} = 1A, t_p = 8/20\mu s, Fwd$		16		V
		$I_{PP} = 8A, t_p = 8/20\mu s, Fwd$		19		V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p = 100ns$		0.4		Ω
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$			8.0	A
ESD Withstand Voltage ¹	V_{ESD}	IEC61000-4-2 (Contact Discharge)	± 30			kV
		IEC61000-4-2 (Air Discharge)	± 30			kV
Diode Capacitance ¹	C_{D-GND}	Reverse Bias=0V, f=1MHz		26	30	pF

Note:

¹ Parameter is guaranteed by design and/or component characterization.

² Transmission Line Pulse (TLP) test setting : Std.TDR(50 Ω), $t_p=100ns$, $t_r=0.2ns$ ITLP and VTLP averaging window: start $t_1=70ns$ to end $t_2=80ns$

SP15-01WTG-C-HV Electrical Characteristics ($T_{OP}=25^\circ C$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1\mu A$			15.0	V
Reverse Breakdown Voltage	V_{BR}	$I_R = 1mA$	16.7			V
Leakage Current	I_{LEAK}	$V_R = 15V$			0.1	μA
Clamp Voltage ¹	V_C	$I_{PP} = 1A, t_p = 8/20\mu s, Fwd$		21		V
		$I_{PP} = 5A, t_p = 8/20\mu s, Fwd$		27		V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p = 100ns$		0.43		Ω
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$			5.0	A
ESD Withstand Voltage ¹	V_{ESD}	IEC61000-4-2 (Contact Discharge)	± 30			kV
		IEC61000-4-2 (Air Discharge)	± 30			kV
Diode Capacitance ¹	$C_{I/O-GND}$	Reverse Bias=0V, f=1MHz		21	24	pF

Note:

¹ Parameter is guaranteed by design and/or component characterization.

² Transmission Line Pulse (TLP) test setting : Std.TDR(50 Ω), $t_p=100ns$, $t_r=0.2ns$ ITLP and VTLP averaging window: start $t_1=70ns$ to end $t_2=80ns$

SPxx Series

100W Discrete Bidirectional TVS Diode

SP24-01WTG-C-HV Electrical Characteristics ($T_{OP}=25^{\circ}\text{C}$)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1\mu\text{A}$			24.0	V
Reverse Breakdown Voltage	V_{BR}	$I_R = 1\text{mA}$	26.7			V
Leakage Current	I_{LEAK}	$V_R = 24\text{V}$			0.1	μA
Clamp Voltage ¹	V_C	$I_{PP} = 1\text{A}$, $t_p = 8/20\mu\text{s}$, Fwd		32		V
		$I_{PP} = 3.0\text{A}$, $t_p = 8/20\mu\text{s}$, Fwd		40		V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p = 100\text{ns}$		0.7		Ω
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu\text{s}$			3.0	A
ESD Withstand Voltage ¹	V_{ESD}	IEC61000-4-2 (Contact Discharge)	± 18			kV
		IEC61000-4-2 (Air Discharge)	± 24			kV
Diode Capacitance ¹	$C_{J(O-GND)}$	Reverse Bias=0V, f=1MHz		13	17	pF

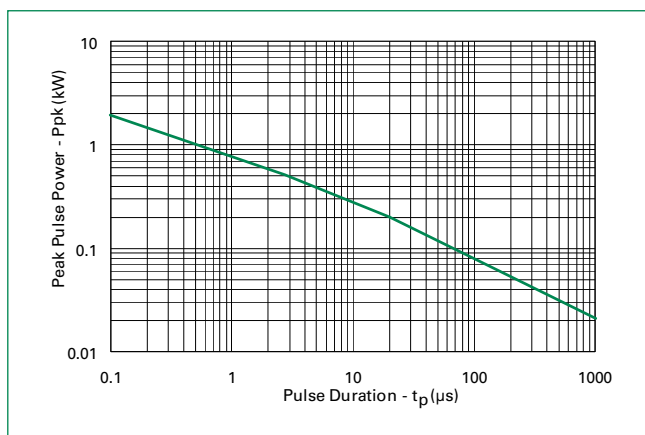
Note:¹ Parameter is guaranteed by design and/or component characterization.² Transmission Line Pulse (TLP) test setting : Std.TDR(50 Ω), $t_p=100\text{ns}$, $t_r=0.2\text{ns}$ ITLP and VTLP averaging window: start $t_1=70\text{ns}$ to end $t_2=80\text{ns}$

SP36-01WTG-C-HV Electrical Characteristics ($T_{OP}=25^{\circ}\text{C}$)

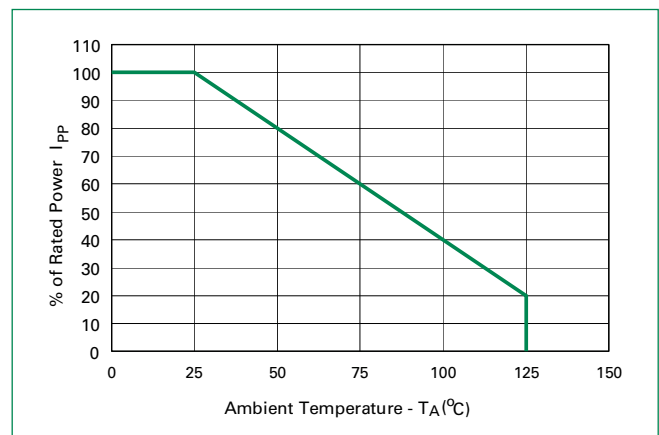
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1\mu\text{A}$			36.0	V
Reverse Breakdown Voltage	V_{BR}	$I_R = 1\text{mA}$	40.0			V
Leakage Current	I_{LEAK}	$V_R = 36\text{V}$			0.1	μA
Clamp Voltage ¹	V_C	$I_{PP} = 1\text{A}$, $t_p = 8/20\mu\text{s}$, Fwd		48		V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p = 100\text{ns}$		1.4		Ω
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu\text{s}$			1.5	A
ESD Withstand Voltage ¹	V_{ESD}	IEC61000-4-2 (Contact Discharge)	± 10			kV
		IEC61000-4-2 (Air Discharge)	± 15			kV
Diode Capacitance ¹	$C_{J(O-GND)}$	Reverse Bias=0V, f=1MHz		10	13	pF

Note:¹ Parameter is guaranteed by design and/or component characterization.² Transmission Line Pulse (TLP) test setting : Std.TDR(50 Ω), $t_p=100\text{ns}$, $t_r=0.2\text{ns}$ ITLP and VTLP averaging window: start $t_1=70\text{ns}$ to end $t_2=80\text{ns}$

Non-Repetitive Peak Pulse Power vs. Pulse Time



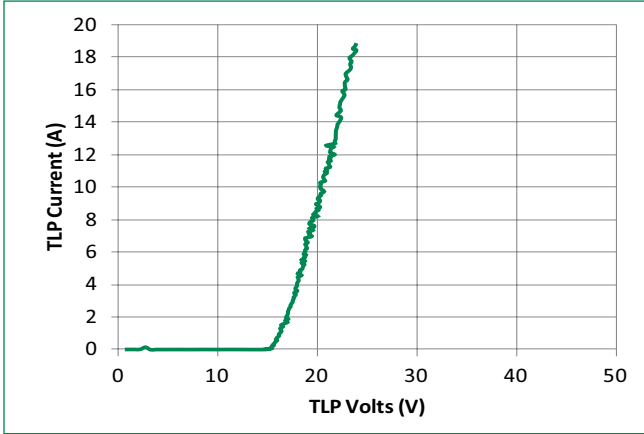
Power Derating Curve



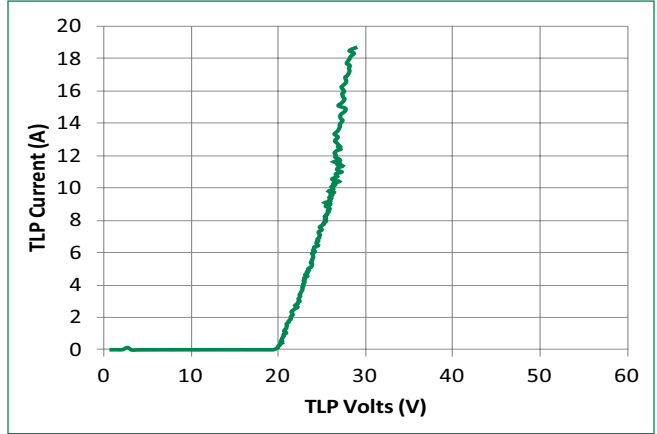
SPxx Series

100W Discrete Bidirectional TVS Diode

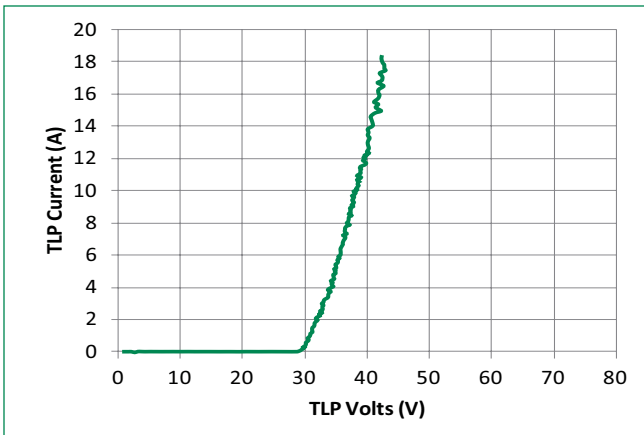
SP12-01WTG-C-HV Transmission Line Pulsing(TLP) Plot



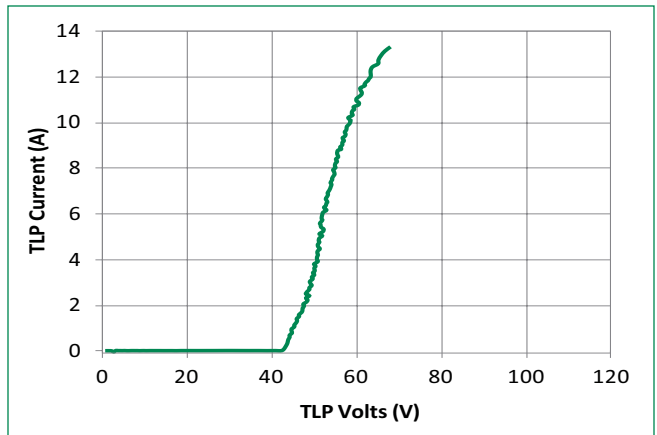
SP15-01WTG-C-HV Transmission Line Pulsing(TLP) Plot



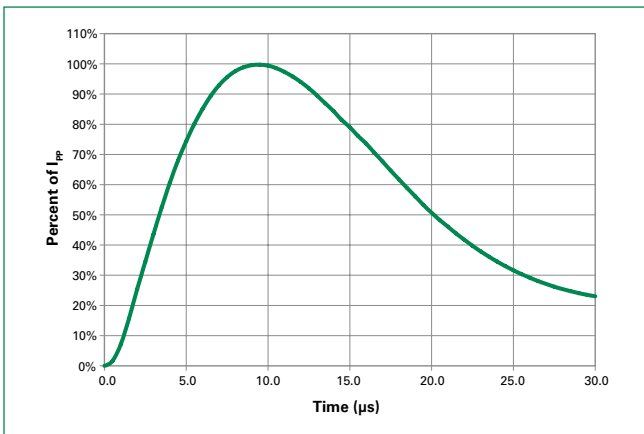
SP24-01WTG-C-HV Transmission Line Pulsing(TLP) Plot



SP36-01WTG-C-HV Transmission Line Pulsing(TLP) Plot



Pulse Waveform

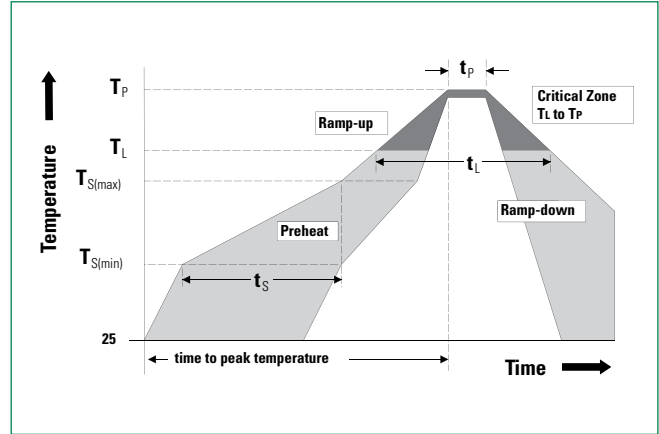


SPxx Series

100W Discrete Bidirectional TVS Diode

Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 120 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{S(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		30 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C



Product Characteristics

Lead Plating	Matte Tin
Lead Material	Copper bump
Substitute Material	Silicon
Flammability	'UL Recognized compound meeting flammability rating V-0

Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Bto is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

Ordering Information

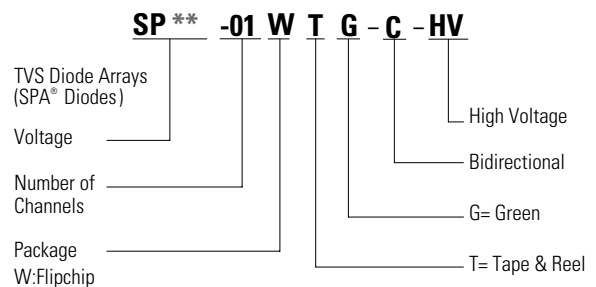
Part Number	Package	Marking	Min. Order Qty.
SP12-01WTG-C-HV	FLIPCHIP	2	10000
SP15-01WTG-C-HV	FLIPCHIP	5	10000
SP24-01WTG-C-HV	FLIPCHIP	4	10000
SP36-01WTG-C-HV	FLIPCHIP	6	10000

Part Marking System



- 2: SP12-01WTG-C-HV
- 5: SP15-01WTG-C-HV
- 4: SP24-01WTG-C-HV
- 6: SP36-01WTG-C-HV

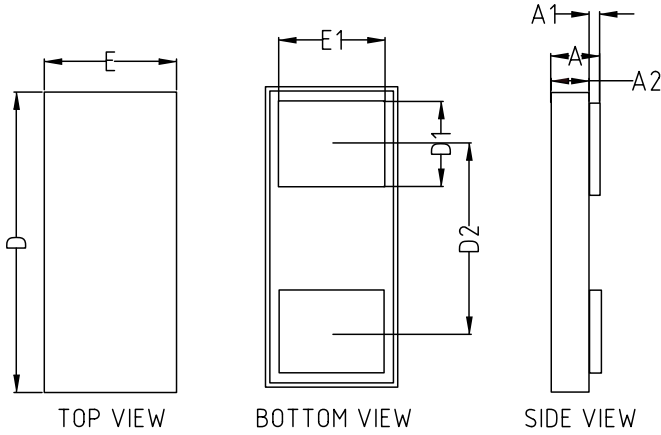
Part Numbering System



SPxx Series

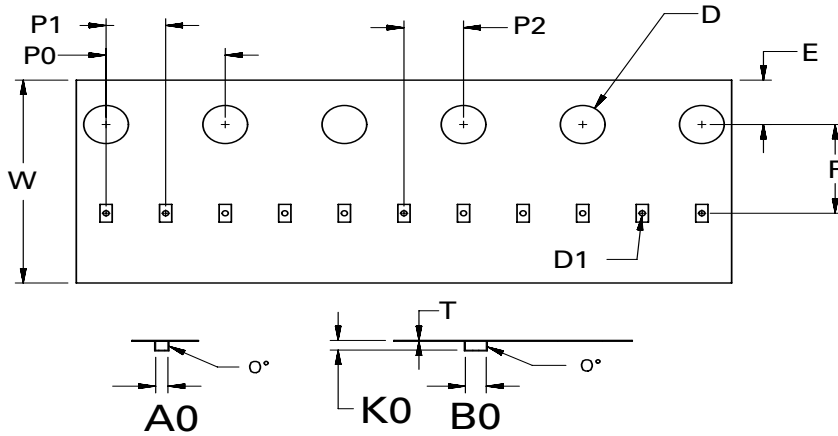
100W Discrete Bidirectional TVS Diode

Package Dimensions – FLIPCHIP

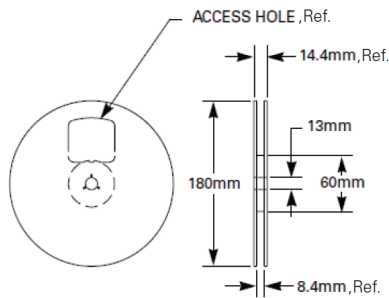


Symbol	Package		FLIPCHIP				
	JEDEC	MO-236					
		Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max	
A	0.273	0.301	0.329	0.011	0.012	0.013	
A1	0.008	0.011	0.014	0.000	0.000	0.001	
A2	0.265	0.290	0.315	0.011	0.012	0.013	
D	0.605	0.640	0.655	0.024	0.026	0.027	
D1	0.145	0.15	0.155	0.006	0.006	0.006	
D2	0.400 REF			0.016 REF			
E	0.305	0.340	0.355	0.012	0.014	0.015	
E1	0.245	0.25	0.255	0.010	0.010	0.010	

Embossed Carrier Tape & Reel Specification – FLIPCHIP



Symbol	Millimeters
A0	0.41+/-0.03
B0	0.70+/-0.03
D	∅ 1.50 + 0.10
D1	∅ 0.20 +/- 0.05
E	1.75+/-0.10
F	3.50+/-0.05
K0	0.38+/-0.03
P0	4.00+/-0.10
P1	2.00+/-0.05
P2	2.00+/-0.05
W	8.00 + 0.30 -0.10
T	0.23+/-0.02



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